

# RJK6013DPP

Silicon N Channel MOS FET  
High Speed Power Switching

REJ03G1582-0100

Rev.1.00

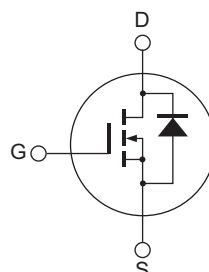
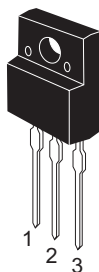
Sep 11, 2007

## Features

- Low on-resistance
- Low leakage current
- High speed switching

## Outline

RENESAS Package code: PRSS0003AB-A  
(Package name: TO-220FN)



1. Gate
2. Drain
3. Source

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	600	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	$I_D$ <sup>Note4</sup>	11	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	33	A
Body-drain diode reverse drain current	$I_{DR}$	11	A
Body-drain diode reverse drain peak current	$I_{DR(pulse)}$ <sup>Note1</sup>	33	A
Avalanche current	$I_{AP}$ <sup>Note3</sup>	4	A
Avalanche energy	$E_{AR}$ <sup>Note3</sup>	0.87	mJ
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	30	W
Channel to case thermal impedance	$\theta_{ch-c}$	4.17	°C/W
Channel temperature	$T_{ch}$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

- Notes: 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$   
 2. Value at  $T_c = 25^\circ C$   
 3.  $ST_{ch} = 25^\circ C$ ,  $T_{ch} \leq 150^\circ C$   
 4. Limited by maximum safe operation area

## Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 600 \text{ V}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	—	4.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.58	0.70	$\Omega$	$I_D = 5.5 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note5</sup>
Input capacitance	$C_{iss}$	—	1450	—	pF	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	$C_{oss}$	—	140	—	pF	
Reverse transfer capacitance	$C_{rss}$	—	17	—	pF	
Turn-on delay time	$t_{d(on)}$	—	33	—	ns	$I_D = 5.5 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 54.5 \Omega$ $R_g = 10 \Omega$
Rise time	$t_r$	—	20	—	ns	
Turn-off delay time	$t_{d(off)}$	—	87	—	ns	
Fall time	$t_f$	—	15	—	ns	
Total gate charge	$Q_g$	—	37.5	—	nC	$V_{DD} = 480 \text{ V}$
Gate to source charge	$Q_{gs}$	—	7.3	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	16.4	—	nC	$I_D = 11 \text{ A}$
Body-drain diode forward voltage	$V_{DF}$	—	0.87	1.45	V	$I_F = 11 \text{ A}$ , $V_{GS} = 0$ <sup>Note5</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	350	—	ns	$I_F = 11 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 5. Pulse test



Notes:

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